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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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R1RP0408DI Series

Wide Temperature Range Version
4M High Speed SRAM (512-kword $\times$ 8-bit)

REJ03C0114-0100Z
Rev. 1.00
Mar.12.2004

Description

The R1RP0408DI Series is a 4-Mbit high speed static RAM organized 512-k word $\times$ 8-bit. It has realized high speed access time by employing CMOS process (6-transistor memory cell) and high speed circuit designing technology. It is most appropriate for the application which requires high speed, high density memory and wide bit width configuration, such as cache and buffer memory in system. It is packaged in 400-mil 36-pin plastic SOJ.

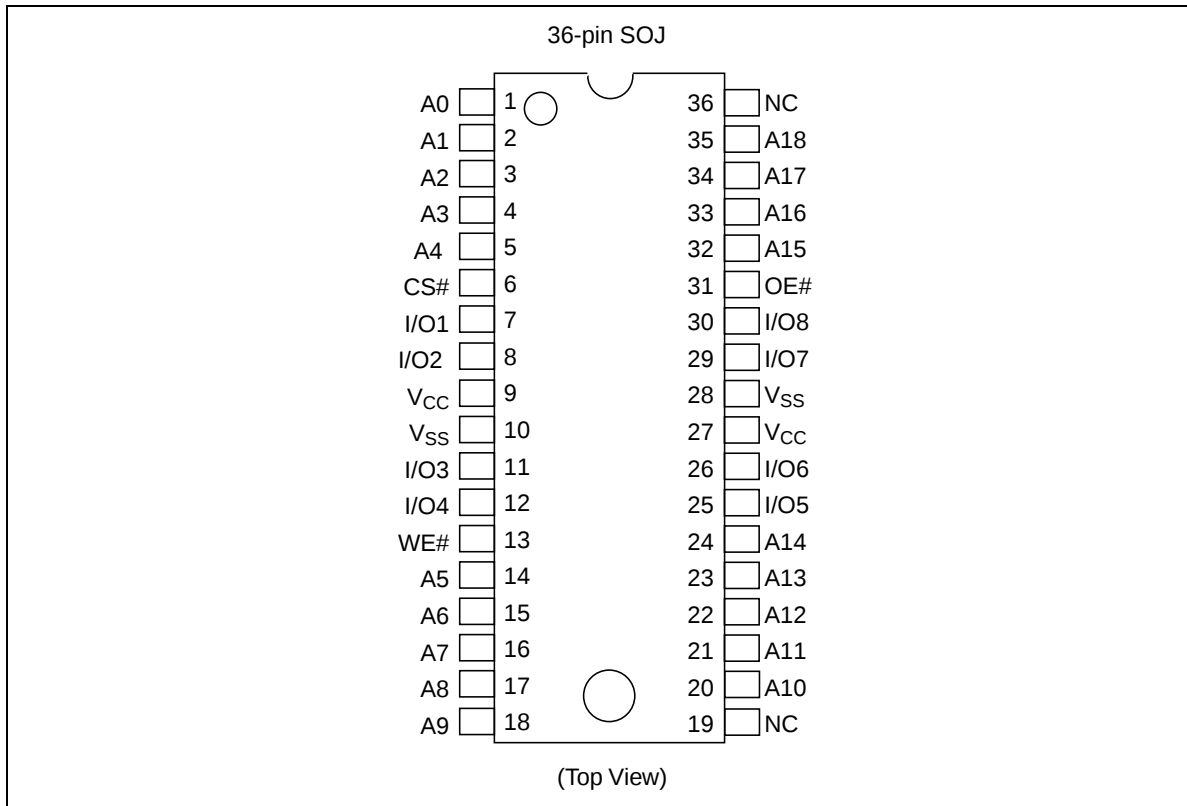
Features

- Single 5.0 V supply: 5.0 V $\pm$ 10 %
- Access time: 12 ns (max)
- Completely static memory
 - No clock or timing strobe required
- Equal access and cycle times
- Directly TTL compatible
 - All inputs and outputs
- Operating current: 130 mA (max)
- TTL standby current: 40 mA (max)
- CMOS standby current: 5 mA (max)
- Center V_{CC} and V_{SS} type pin out
- Temperature range: -40 to $+85^{\circ}\text{C}$

Ordering Information

Type No.	Access time	Package
R1RP0408DGE-2PI	12 ns	400-mil 36-pin plastic SOJ (36P0K)

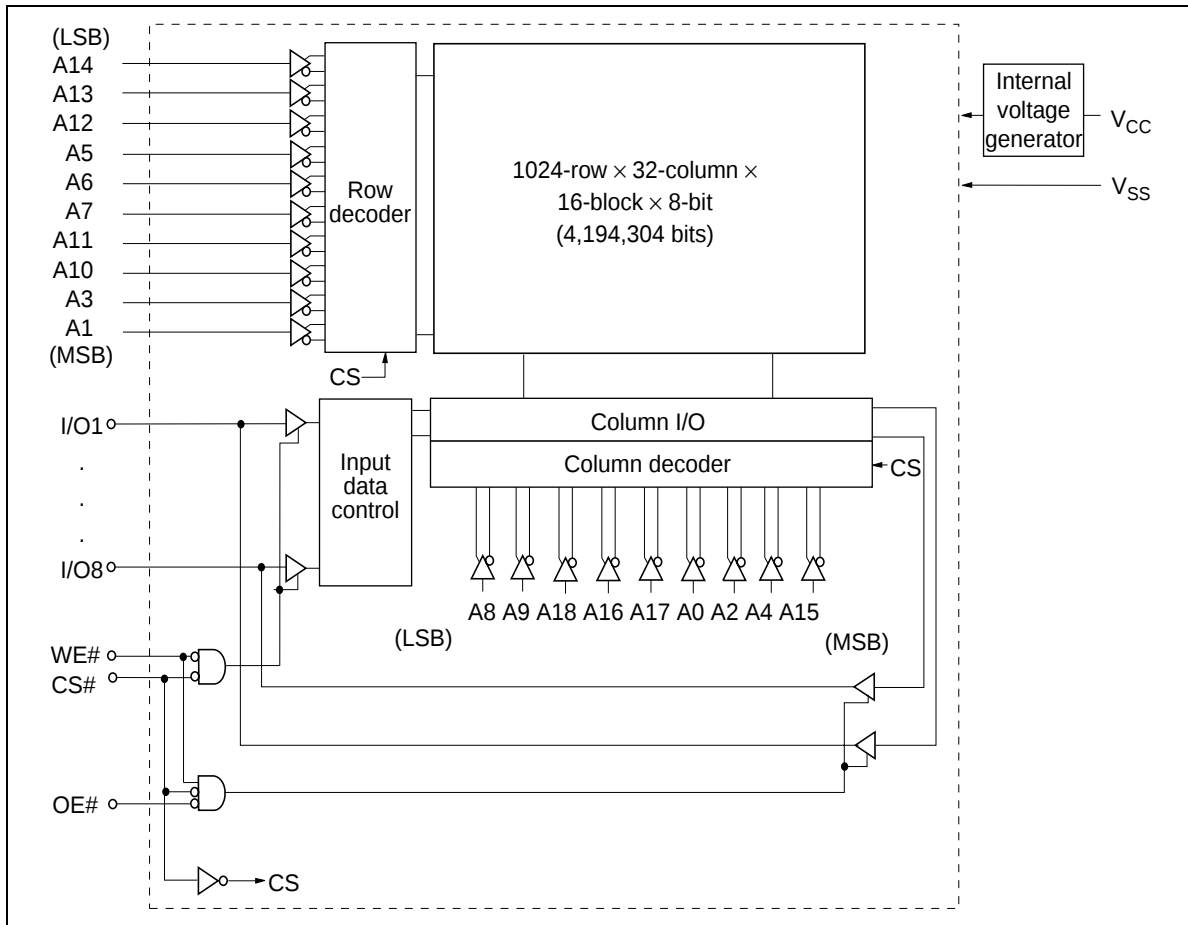
Pin Arrangement



Pin Description

Pin name	Function
A0 to A18	Address input
I/O1 to I/O8	Data input/output
CS#	Chip select
OE#	Output enable
WE#	Write enable
V _{CC}	Power supply
V _{SS}	Ground
NC	No connection

Block Diagram



Operation Table

CS#	OE#	WE#	Mode	V _{CC} current	I/O	Ref. cycle
H	×	×	Standby	I _{SB} , I _{SB1}	High-Z	—
L	H	H	Output disable	I _{CC}	High-Z	—
L	L	H	Read	I _{CC}	D _{OUT}	Read cycle (1) to (3)
L	H	L	Write	I _{CC}	D _{IN}	Write cycle (1)
L	L	L	Write	I _{CC}	D _{IN}	Write cycle (2)

Note: H: V_{IH}, L: V_{IL}, ×: V_{IH} or V_{IL}

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply voltage relative to V _{SS}	V _{CC}	−0.5 to +7.0	V
Voltage on any pin relative to V _{SS}	V _T	−0.5* ¹ to V _{CC} + 0.5* ²	V
Power dissipation	P _T	1.0	W
Operating temperature	Topr	−40 to +85	°C
Storage temperature	Tstg	−55 to +125	°C
Storage temperature under bias	Tbias	−40 to +85	°C

Notes: 1. V_T (min) = −2.0 V for pulse width (under shoot) ≤ 6 ns.
 2. V_T (max) = V_{CC} + 2.0 V for pulse width (over shoot) ≤ 6 ns.

Recommended DC Operating Conditions

(Ta = −40 to +85°C)

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V _{CC} * ³	4.5	5.0	5.5	V
	V _{SS} * ⁴	0	0	0	V
Input voltage	V _{IH}	2.2	—	V _{CC} + 0.5* ²	V
	V _{IL}	−0.5* ¹	—	0.8	V

Notes: 1. V_{IL} (min) = −2.0 V for pulse width (under shoot) ≤ 6 ns.
 2. V_{IH} (max) = V_{CC} + 2.0 V for pulse width (over shoot) ≤ 6 ns.
 3. The supply voltage with all V_{CC} pins must be on the same level.
 4. The supply voltage with all V_{SS} pins must be on the same level.

DC Characteristics

(Ta = -40 to +85°C, V_{CC} = 5.0 V ± 10 %, V_{SS} = 0 V)

Parameter	Symbol	Min	Max	Unit	Test conditions
Input leakage current	I _{LI}	—	2	μA	V _{IN} = V _{SS} to V _{CC}
Output leakage current	I _{LO}	—	2	μA	V _{IN} = V _{SS} to V _{CC}
Operation power supply current	I _{CC}	—	130	mA	Min cycle CS# = V _{IL} , I _{OUT} = 0 mA Other inputs = V _{IH} /V _{IL}
Standby power supply current	I _{SB}	—	40	mA	Min cycle, CS# = V _{IH} , Other inputs = V _{IH} /V _{IL}
	I _{SB1}	—	5	mA	f = 0 MHz V _{CC} ≥ CS# ≥ V _{CC} - 0.2 V, (1) 0 V ≤ V _{IN} ≤ 0.2 V or (2) V _{CC} ≥ V _{IN} ≥ V _{CC} - 0.2 V
Output voltage	V _{OL}	—	0.4	V	I _{OL} = 8 mA
	V _{OH}	2.4	—	V	I _{OH} = -4 mA

Capacitance

(Ta = +25°C, f = 1.0 MHz)

Parameter	Symbol	Min	Max	Unit	Test conditions
Input capacitance* ¹	C _{IN}	—	6	pF	V _{IN} = 0 V
Input/output capacitance* ¹	C _{I/O}	—	8	pF	V _{I/O} = 0 V

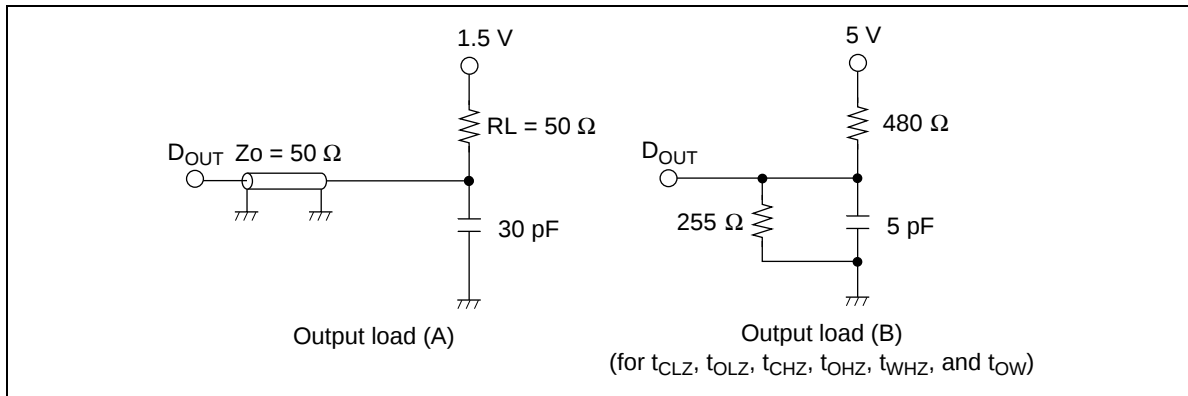
Note: 1. This parameter is sampled and not 100% tested.

AC Characteristics

($T_a = -40$ to $+85^\circ\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$, unless otherwise noted.)

Test Conditions

- Input pulse levels: 3.0 V/0.0 V
- Input rise and fall time: 3 ns
- Input and output timing reference levels: 1.5 V
- Output load: See figures (Including scope and jig)



Read Cycle

Parameter	Symbol	R1RP0408DI		Unit	Notes
		Min	Max		
Read cycle time	t_{RC}	12	—	ns	
Address access time	t_{AA}	—	12	ns	
Chip select access time	t_{ACS}	—	12	ns	
Output enable to output valid	t_{OE}	—	6	ns	
Output hold from address change	t_{OH}	3	—	ns	
Chip select to output in low-Z	t_{CLZ}	3	—	ns	1
Output enable to output in low-Z	t_{OLZ}	0	—	ns	1
Chip deselect to output in high-Z	t_{CHZ}	—	6	ns	1
Output disable to output in high-Z	t_{OHZ}	—	6	ns	1

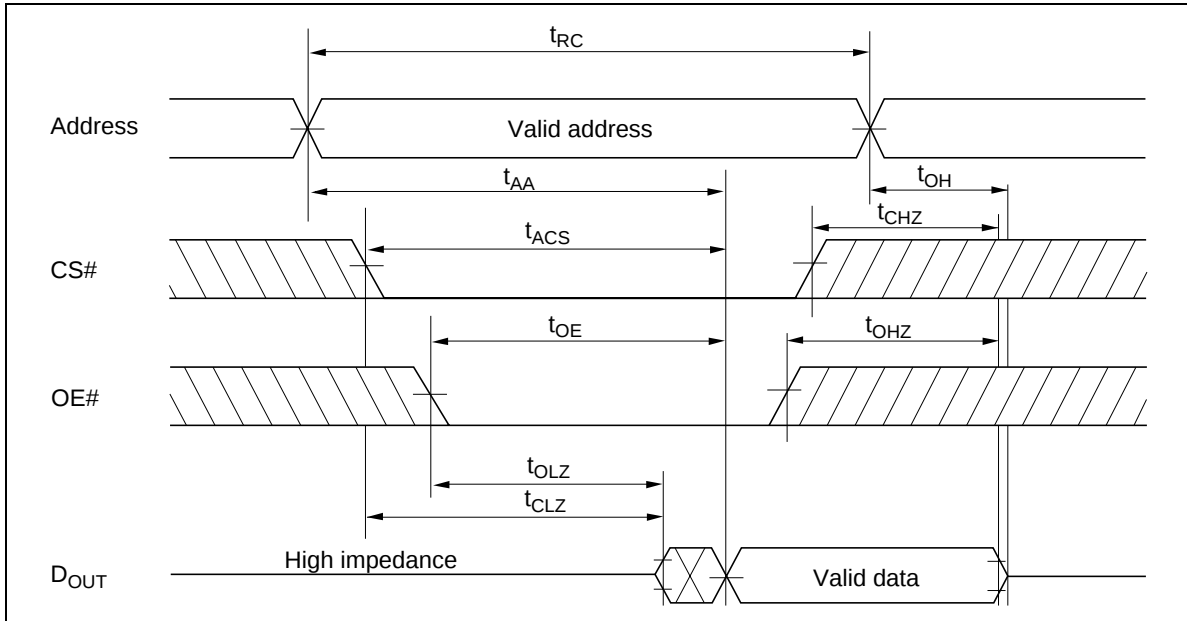
Write Cycle

		R1RP0408DI			
		-2			
Parameter	Symbol	Min	Max	Unit	Notes
Write cycle time	t _{WC}	12	—	ns	
Address valid to end of write	t _{AW}	8	—	ns	
Chip select to end of write	t _{CW}	8	—	ns	9
Write pulse width	t _{WP}	8	—	ns	8
Address setup time	t _{AS}	0	—	ns	6
Write recovery time	t _{WR}	0	—	ns	7
Data to write time overlap	t _{DW}	6	—	ns	
Data hold from write time	t _{DH}	0	—	ns	
Write disable to output in low-Z	t _{OW}	3	—	ns	1
Output disable to output in high-Z	t _{OHZ}	—	6	ns	1
Write enable to output in high-Z	t _{WHZ}	—	6	ns	1

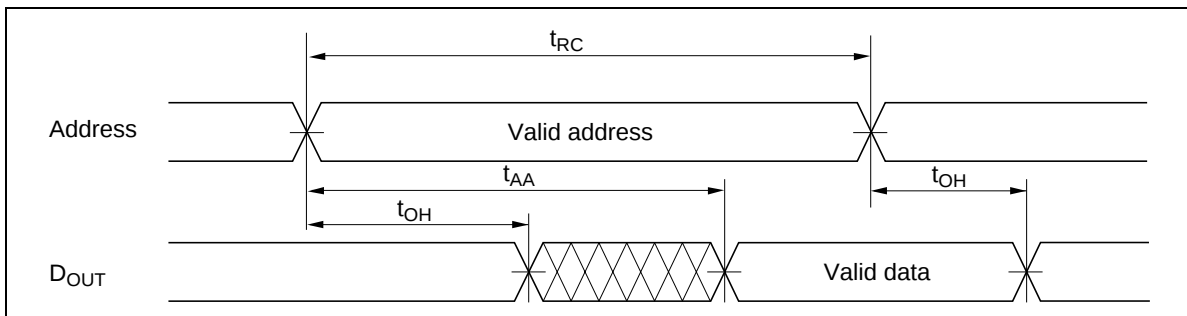
- Notes:
1. Transition is measured ± 200 mV from steady voltage with output load (B). This parameter is sampled and not 100% tested.
 2. Address should be valid prior to or coincident with CS# transition low.
 3. WE# and/or CS# must be high during address transition time.
 4. If CS# and OE# are low during this period, I/O pins are in the output state. Then, the data input signals of opposite phase to the outputs must not be applied to them.
 5. If the CS# low transition occurs simultaneously with the WE# low transition or after the WE# transition, output remains a high impedance state.
 6. t_{AS} is measured from the latest address transition to the later of CS# or WE# going low.
 7. t_{WR} is measured from the earlier of CS# or WE# going high to the first address transition.
 8. A write occurs during the overlap of a low CS# and a low WE#. A write begins at the latest transition among CS# going low and WE# going low. A write ends at the earliest transition among CS# going high and WE# going high. t_{WP} is measured from the beginning of write to the end of write.
 9. t_{CW} is measured from the later of CS# going low to the end of write.

Timing Waveforms

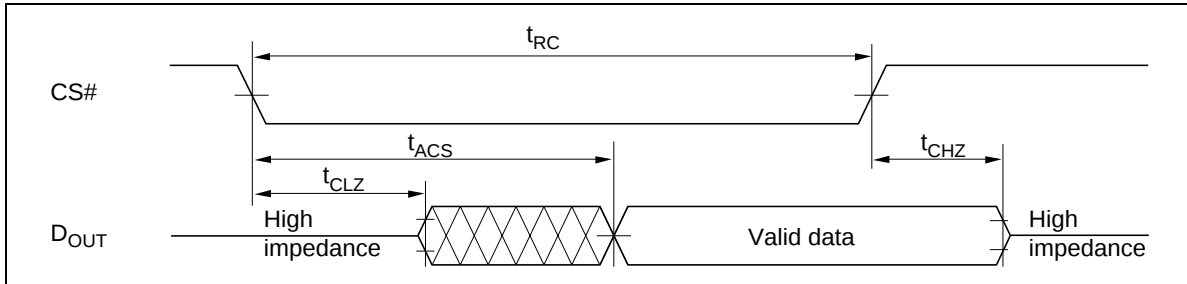
Read Timing Waveform (1) ($WE\# = V_{IH}$)



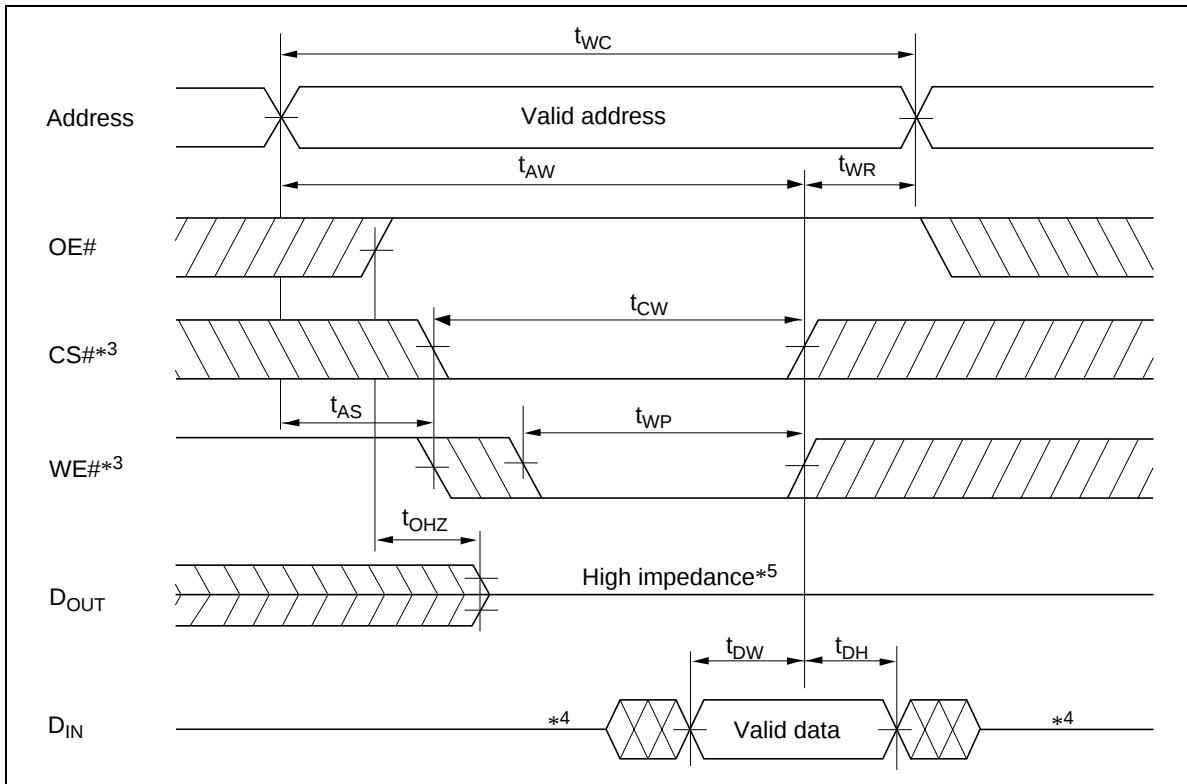
Read Timing Waveform (2) ($WE\# = V_{IH}$, $CS\# = V_{IL}$, $OE\# = V_{IL}$)



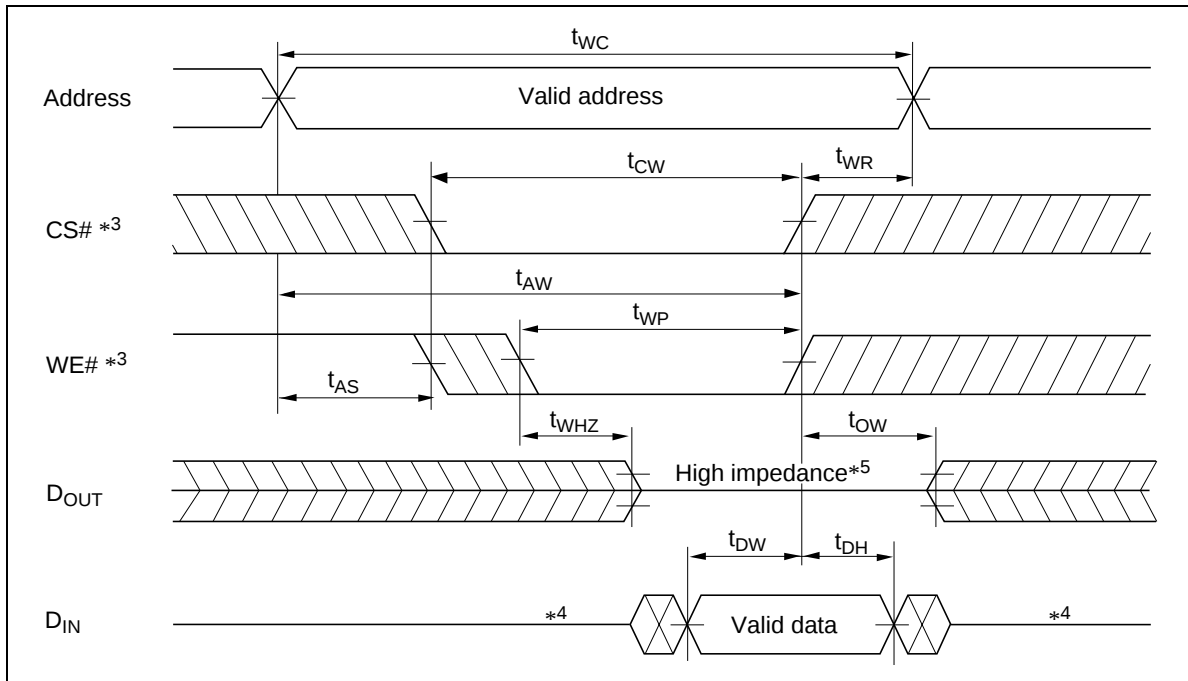
Read Timing Waveform (3) ($WE\# = V_{IH}$, $CS\# = V_{IL}$, $OE\# = V_{IL}$)*²



Write Timing Waveform (1) ($WE\#$ Controlled)



Write Timing Waveform (2) (CS# Controlled)



Revision History

R1RP0408DI Series Data Sheet

Rev.	Date	Contents of Modification	
		Page	Description
0.01	Oct. 01, 2003	—	Initial issue
1.00	Mar.12.2004	—	Deletion of Preliminary

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